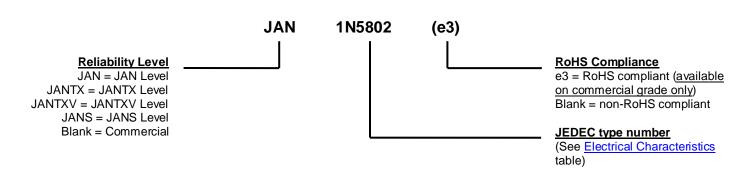


## **MECHANICAL and PACKAGING**

- CASE: Hermetically sealed voidless hard glass with tungsten slugs.
- TERMINALS: Tin/lead (Sn/Pb) or RoHS compliant matte/tin (commercial grade only) over nickel plate over copper.
- MARKING: Body coated in blue with part number.
- POLARITY: Cathode indicated by band.
- TAPE & REEL option: Standard per EIA-296. Consult factory for quantities.
- WEIGHT: 340 milligrams.
- See Package Dimensions on last page.

## PART NOMENCLATURE



SYMBOLS & DEFINITIONS						
Symbol	Definition					
$V_{BR}$	Minimum Breakdown Voltage: The minimum voltage the device will exhibit at a specified current.					
V <sub>RWM</sub>	Working Peak Reverse Voltage: The maximum peak voltage that can be applied over the operating temperature range.					
Io	Average Rectified Output Current: Output current averaged over a full cycle with a 50 Hz or 60 Hz sine-wave input and a 180 degree conduction angle.					
V <sub>F</sub>	Maximum Forward Voltage: The maximum forward voltage the device will exhibit at a specified current.					
I <sub>R</sub>	Maximum Leakage Current: The maximum leakage current that will flow at the specified voltage and temperature.					
С	Capacitance: The capacitance in pF at a frequency of 1 MHz and specified voltage.					
t <sub>rr</sub>	Reverse Recovery Time: The time interval between the instant the current passes through zero when changing from the forward direction to the reverse direction and a specified recovery decay point after a peak reverse current occurs.					

## **ELECTRICAL CHARACTERISTICS**

	BREAKDOWN VOLTAGE (MIN.)	MAXIMUM FORWARD VOLTAGE @ 8.3 ms pulse		REVE CURF (MA	RENT	SURGE CURRENT (MAX)	REVERSE RECOVERY TIME (MAX)	THERMAL IMPEDANCE @ t <sub>H</sub> = 10 ms
	@ 100 μA V <sub>(BR)</sub>	V	FM	@ V	RWM R	I <sub>FSM</sub> (Note 1)	t <sub>rr</sub> (Note 2)	Z <sub>OJX</sub> (Note 3)
TYPE	(=:-)	Volts		μ		, ,	,	,
	Volts	I <sub>F</sub> = 1.0 A	$I_F = 2.5 A$	25 °C	125 °C	Amps	ns	°C/W
1N5802	60	0.875	0.975	1	175	35	25	4.0
1N5804	110	0.875	0.975	1	175	35	25	4.0
1N5806	160	0.875	0.975	1	175	35	25	4.0

**NOTES:** 1.  $T_A = 2.5$  °C @  $I_O = 1.0$  A and  $V_{RWM}$  for ten 8.3 ms surges at 1 minute intervals ( $I_{FSM}$  surge is also a maximum rating).

- 2. I<sub>F</sub> = 0.5 A, I<sub>RM</sub> = 0.5 A, I<sub>R(REC)</sub> = .05 A (t<sub>rr</sub> reverse recovery time is also a maximum rating).
- 3. For the complete thermal impedance curve over a broad range of heating times, see Figure 1.



## **GRAPHS**

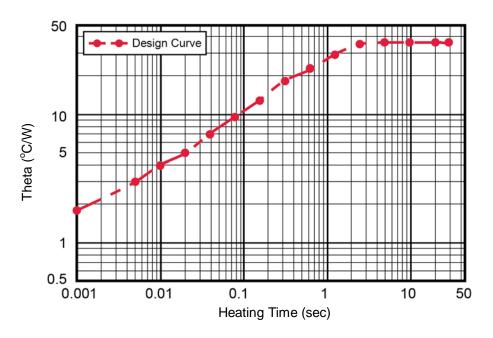


FIGURE 1

Maximum Thermal Impedance

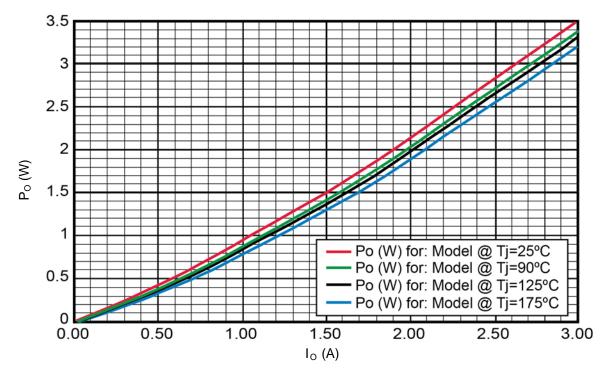


FIGURE 2
Rectifier Power vs I<sub>O</sub> (Average Forward Current)



# **GRAPHS** (continued)

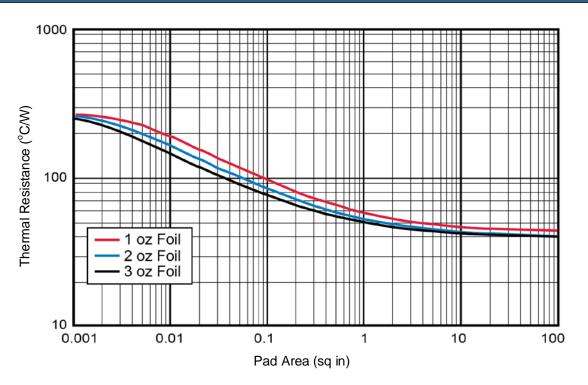


FIGURE 3

Thermal Resistance vs FR4 Pad Area At Ambient
PCB horizontal (for each pad) with 1, 2, and 3 oz copper

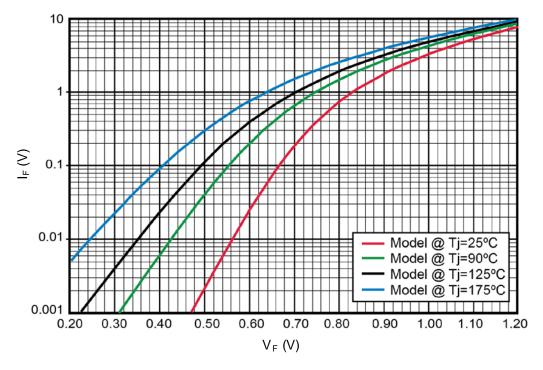
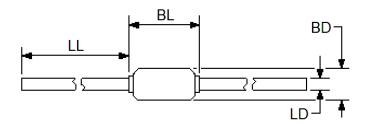


FIGURE 4
Forward Voltage vs Forward Current



# **PACKAGE DIMENSIONS**



#### **NOTES:**

- 1. Dimensions are in inches.
- 2. Millimeters are given for general information only.
- 3. Dimension BL shall include the entire body including slugs and sections of the lead over which the diameter is uncontrolled. This uncontrolled area is defined as the zone between the edge of the diode body and extending .050 inch (1.27 mm) onto the leads.
- 4. Dimension BD shall be measured at the largest diameter.
- In accordance with ASME Y14.5M, diameters are equivalent to Φx symbology.

Ltr	IN	CH	MILLIM	Notes	
	Min	Max	Min	Max	
BD	.065	.085	1.65	2.16	4
BL	.125	.250	3.18	6.35	3
LD	.027	.032	0.69	0.81	3
LL	.700	1.30	17.78	33.02	